

T493B336M006BH6120

Aliases (DLA Drawing 07016-013MBHZ)

T493 HRA, Tantalum, MnO2 Tantalum, HRA, 33 uF, 20%, 6.3 VDC, SMD, MnO2, Molded, DLA Drawing, B (0.1%/1000 Hrs), 600 mOhms, 2.1 mm, 1411 / 3528



Click [here](#) for the 3D model.

General Information

Series	T493 HRA
Dielectric	MnO2 Tantalum
Style	SMD Chip
Description	SMD, MnO2, Molded, DLA Drawing
RoHS	No
Prop 65	WARNING: Cancer and reproductive harm - https://www.p65warnings.ca.gov/
SCIP Number	1dd2e1b8-26dd-4d52-927c-6f9d519011aa
Termination	Tin Lead (SnPb)
Typical Component Weight	102.3 mg

Dimensions

L	3.5mm +/-0.2mm
W	2.8mm +/-0.2mm
H	1.9mm +/-0.2mm
S	0.8mm +/-0.3mm
F	2.2mm +/-0.1mm

Packaging Specifications

Packaging	T&R, 178mm
Packaging Quantity	2000

Specifications

Capacitance	33 uF
Tolerance	20%
Voltage DC	6.3 VDC (85C), 4.22 VDC (125C)
Temperature Range	-55/ +125°C
Rated Temperature	85°C
Dissipation Factor	6% 120Hz 25C
Failure Rate	B (0.1%/1000 Hrs)
ESR	0.6 Ohms (100kHz 25C)
Ripple Current	376 mA (rms, 100kHz 25C)
Leakage Current	2.1 uA (5min 25°C)
Testing and Reliability	Standard Testing Only

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